



TET ESTEL AS
ESTONIA

**December
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**Series
D472-400
D472-400X**

**Rectifier Stud-Mounted
Diodes
Type D472-400,
D472-400X**

Designed for rectifiers and industrial applications

Maximum mean forward current	I_{FAV} 400 A					
Maximum repetitive peak reverse voltage	U_{RRM} 2200 ÷ 3200 V					
Reverse recovery time	trr (typ) 30 µs					
U _{RRM} , V	2200	2400	2600	2800	3000	3200
Voltage code	22	24	26	28	30	32
T _{vj} , °C	- 60 ÷ 150					

MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	D472-400 D472-400X	Conditions		
I _{FAV}	Mean forward current	A	400 595	T _c =100 °C, T _c =70 °C, 180° half-sine wave, 50 Hz		
I _{FRMS}	RMS forward current	A	628	T _c =100°C		
I _{FSM}	Surge forward current	kA	10 11	T _{vj} =150°C T _{vj} = 25°C	tp=10 ms U _R =0	
I ² t	Limiting load integral	kA ² s	500 605	T _{vj} =150°C T _{vj} = 25°C		
U _{RRM}	Repetitive peak reverse voltage	V	2200÷3200	T _{j min} ≤T _{vj} ≤T _{jM} 180° half-sine wave, 50 Hz		
U _{RSR}	Non-repetitive peak reverse voltage	V	2300÷3300	T _{j min} ≤T _{vj} ≤T _{jM} 180° half-sine wave tp=10 ms, Single pulse		
T _{stg}	Storage temperature	°C	-60÷80			
T _{vj}	Junction temperature	°C	-60÷150			

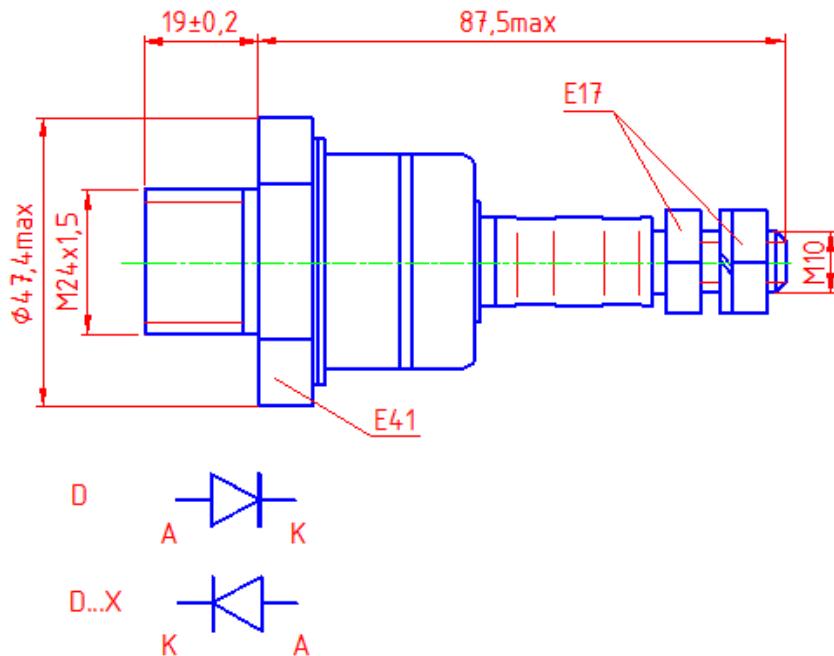
CHARACTERISTICS

U _{FM}	Peak forward voltage	V	1,5	T _{vj} =25°C, I _{FM} =3,14 I _{FAV}
U _{F(TO)}	Threshold voltage	V	0,9	T _{vj} =150°C 1,57 I _{FAV} < I _F <4,71 I _{FAV}
R _T	Forward slope resistance	mΩ	0,4	
I _{RRM}	Repetitive peak reverse current	mA	50	T _{vj} =150°C, U _R = U _{RRM}

CHARACTERISTICS				
Symbols and parameters		Units	D472-400 D472-400X	Conditions
Qrr	Recovered charge (typ)	µC	1500	Tvj=150°C, If=400A, Ur=100V dir / dt = 10A/µs
trr	Reverse recovery time (typ)	µS	30	
Irrm	Peak reverse recovery current (typ)	A	100	
Rthjc	Thermal resistance junction to case	°C/W	0,09	Direct current

ORDERING					
	D	472	400	X	32
	1	2	3	4	5

1. Diode.
2. Design version.
3. Mean forward current, A.
4. Reverse polarity (cathode stud mounted), without X-normal polarity.
5. Voltage code (32 = 3200 V).



Mounting of diodes with a rigid cathode gate should be carried through a flexible conductor.

Tightening torque: 40 ÷ 60 Nm (thread M24x1,5)

Tightening torque: 8 ÷ 12 Nm (thread M10)

Weight : 380 grams